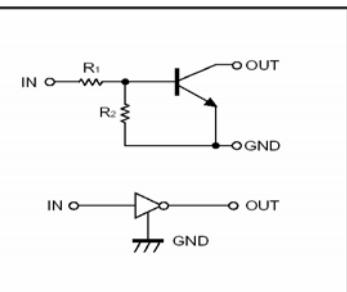


Features

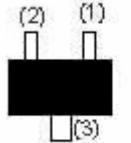
- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTC123YE

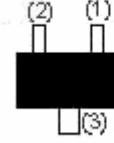


1.IN
2.GND
3.OUT

SOT-523

Addreviated symbol: 62

DTC123YUA

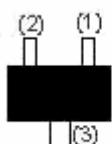


1.IN
2.GND
3.OUT

SOT-323

Addreviated symbol: 62

DTC123YKA

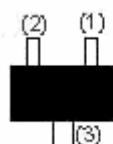


1.IN
2.GND
3.OUT

SOT-23-3L

Addreviated symbol: 62

DTC123YCA

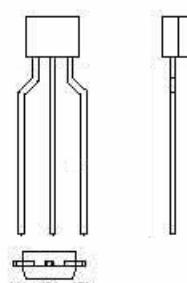


1.IN
2.GND
3.OUT

SOT-23

Addreviated symbol: 62

DTC123YSA



1.GND
2.OUT
3.IN

TO-92S

Absolute maximum ratings(Ta=25°C)

Digital Transistor(NPN)

Parameter	Symbol	Limits (DTC123Y□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}	50					V
Input voltage	V _{IN}	-5~12					V
Output current	I _O	100					mA
	I _{C(MAX)}	100					
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j	150					°C
Storage temperature	T _{stg}	-55~150					°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.3	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	3				V _O =0.3V, I _O =20mA
Output voltage	V _{O(on)}		0.1	0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I			3.8	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V, V _I =0
DC current gain	G _i	33				V _O =5V, I _O =10mA
Input resistance	R ₁	1.54	2.2	2.86	KΩ	-
Resistance ratio	R ₂ /R ₁	3.6	4.5	5.5		-
Transition frequency	f _T		250		MHz	V _O =10V, I _O =5mA, f=100MHz

Typical Characteristics

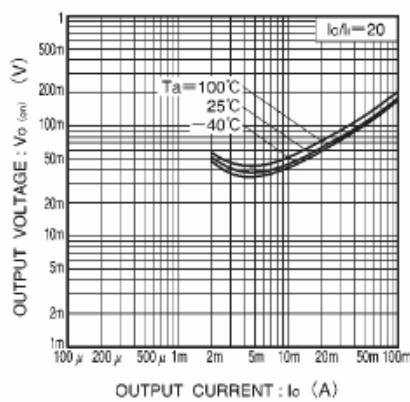
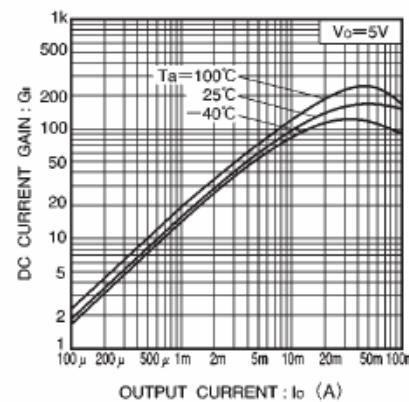
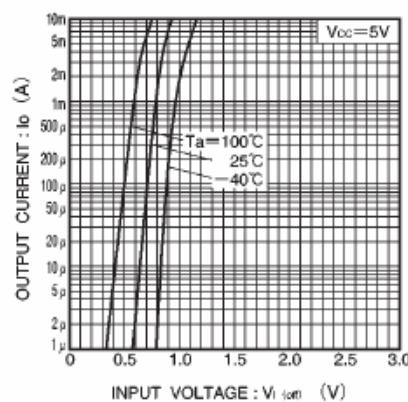
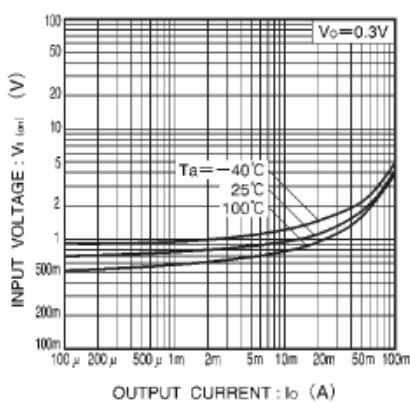


Fig.4 Output voltage vs. output current